# NSN 5961-00-755-4350

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.410 inches

#### Terminal Length:

0.370 inches

#### **Overall Diameter:**

1.560 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### **Terminal Circle Diameter:**

0.430 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Germanium

#### Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

12.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

80.0 degrees celsius junction

#### **Special Features:**

Two no. 16 mtg holes spaced 1.187 in. C to c; junction pattern arrangement: pnp

## Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

## **Specification Data:**

80131-release1748 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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